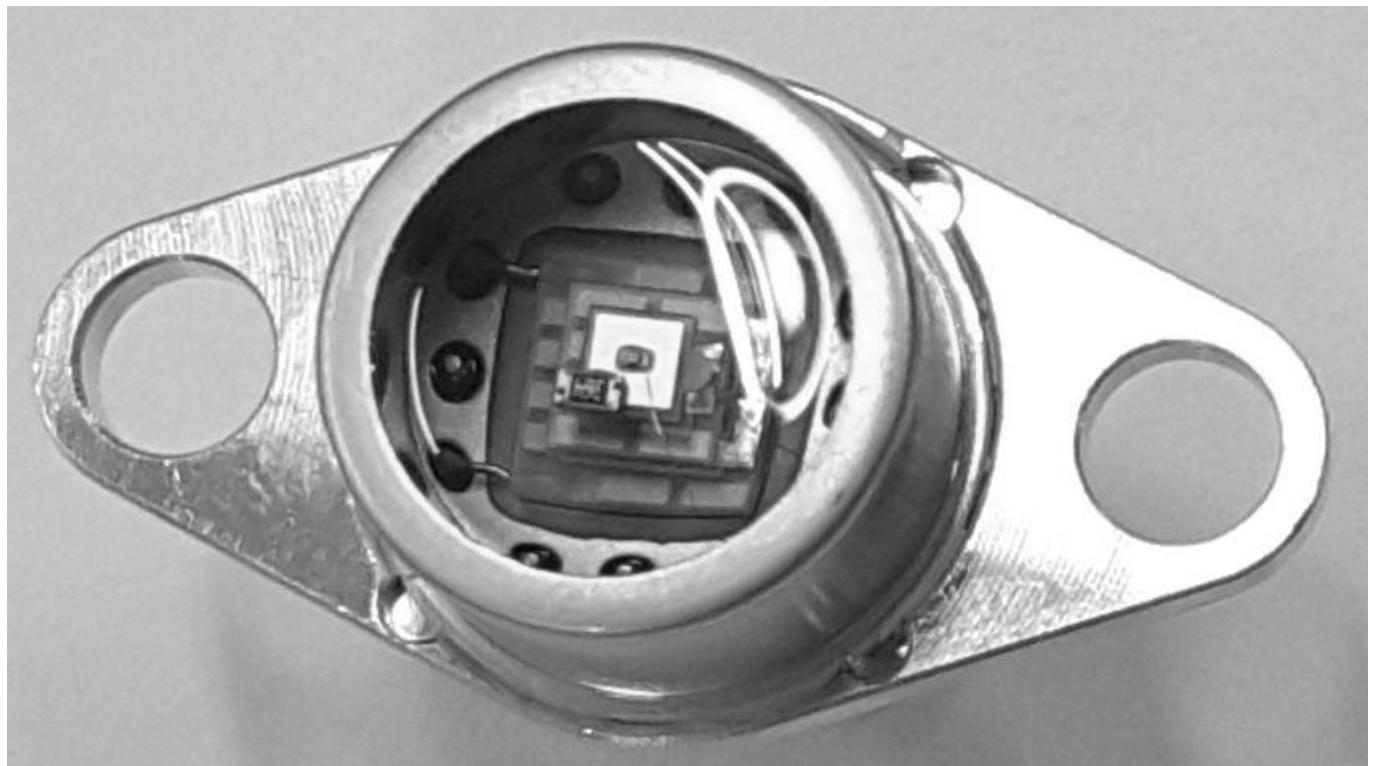


NFAD with TEC

(TO-8 Negative Feedback Avalanche Diode)



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General Description

InGaAs NFAD (Negative Feedback Avalanche Diode) is used for photon counting such as ultra-long distance Light Detection and Ranging (LiDAR) and Laser Range Finder (LRF), Free Space Quantum Communication, anything requires minute photon counting application, such as Gas sensors and Bio sensors, etc. It is based on the theory of low noise and high speed photo detection system using optical feedback with a current amplification function.

Features

- Free Running Mode operation
- Built-in Quenching Resistor (Available Option : 360 kΩ/ 510 kΩ/ 680 kΩ/ 810 kΩ/ 1MΩ)
- Optimized for 1000 nm to 1600 nm Wavelength
- Free Space
- Built in 3-stage Cooling System (TEC)
- Customized PIN map available

Applications

- Gas Leakage Sensor
- Quantum Cryptography (QKD)
- Light Detection and Ranging (LiDAR)
- Free Space Optical Communication
- Fundamental Studies in Quantum Physics

Absolute Maximum Ratings

| Parameter | Conditions | Rating(Max.) | Unit |
|---------------------|-----------------------------|--------------|------|
| Forward Current | Continuous bias | 1 | mA |
| Forward Voltage | Continuous bias | 1 | V |
| Reverse Current | Continuous bias | 1 | mA |
| Reverse Voltage | DC Bias (free-running mode) | $V_{BR} + 5$ | V |
| Optical Input Power | Continuous wave | 1 | mW |
| TEC Current | @27°C, Vacuum | 2.6 | A |
| TEC Voltage | @27°C, Vacuum | 2.0 | V |
| Thermistor | @25°C | 10 | kΩ |
| Storage Temperature | - | -40 to +85 | °C |

Table 1. Absolute Maximum Ratings

Electro-Optical Characteristics

Inspection sheet shall be appended to products when they are delivered. Test report shall be submitted in papers and in electronic media. It shall contain the major in following items.

Optical Characteristics ($T_c=25^{\circ}\text{C}$)

| Parameter | Symbol | Test Condition | Min | Typ. | Max | Unit |
|-------------------------------------|-----------|------------------------------------|------|------|------|-----------------------|
| Breakdown Voltage | V_{BR} | $I_D=0.1\mu\text{A}$ | 60 | 70 | 80 | V |
| Total dark current | I_D | $V_R = 0.95V_{BR}$ | | 1 | | nA |
| Capacitance | C_{PD} | $f = 1\text{MHz}, V_{PD} = 0.9V_B$ | | 0.1 | | pF |
| Quantum efficiency | η | $M=1, 1550\text{nm}$ | | 70 | | % |
| Optical Wavelength Range | λ | - | 1000 | | 1600 | nm |
| Responsivity | R | $\lambda = 1550\text{nm}, M=1$ | 0.7 | 0.8 | | A/W |
| Temperature coefficient of V_{BR} | Γ | $\Delta V_{BR}/\Delta T$ | | 0.11 | | V/ $^{\circ}\text{C}$ |

Table 2. Optical Characteristics

Optical Characteristics ($T_c= -40^{\circ}\text{C}$)

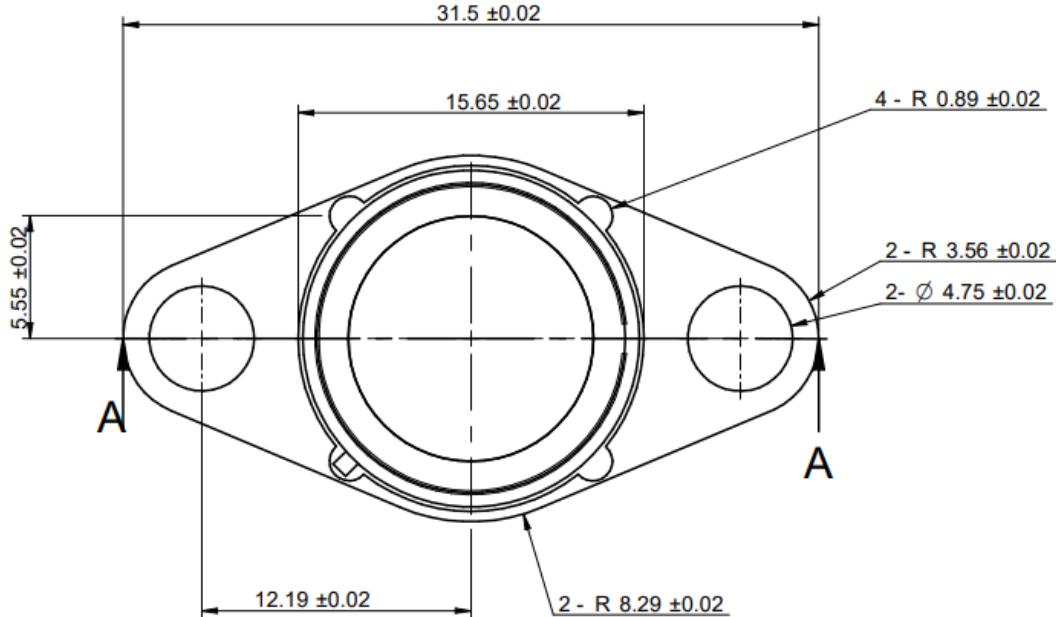
| Parameter | Symbol | Test Condition | Min | Typ. | Max | Unit |
|-----------------------------|------------|----------------------------------------|-----|------|-----|------|
| Photon Detection efficiency | PDE | $T_c=-40^{\circ}\text{C}$ | 10 | | | % |
| Dark count rate | DCR | @ 10% PDE $T_c=-40^{\circ}\text{C}$ | | | 10 | KHz |
| Operating Excess voltage | ΔV | | | +2 | | V |

Table 3. Optical Characteristics at GM operation

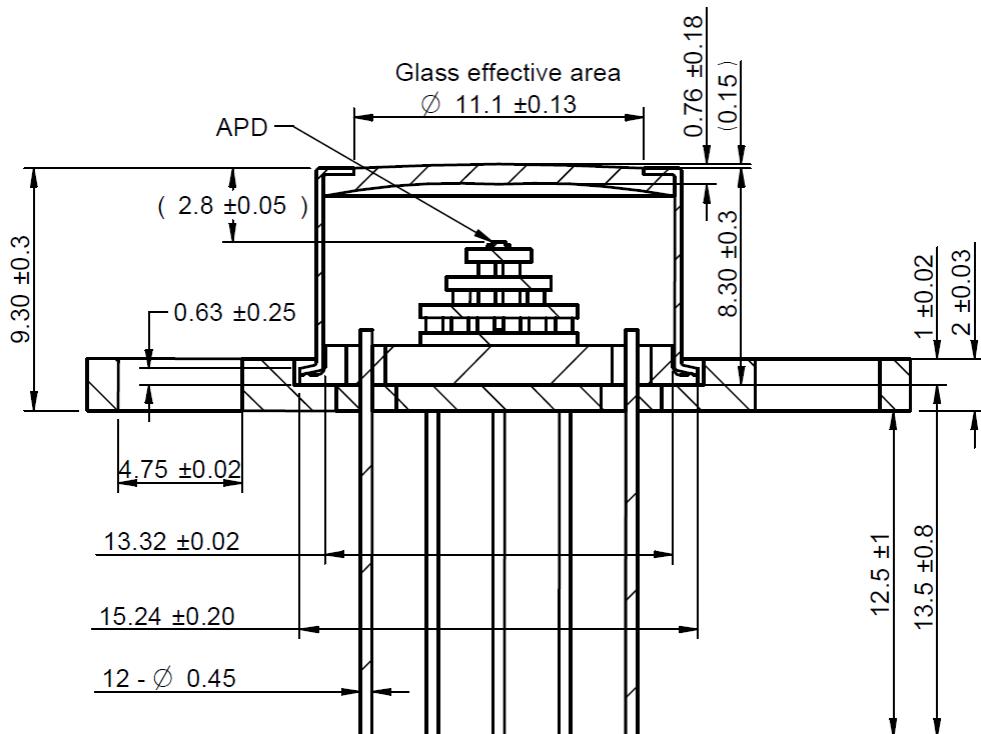
* Note : Optical characteristics are based on the measurement result with pigtails.

Mechanical Dimension & Pin Layout

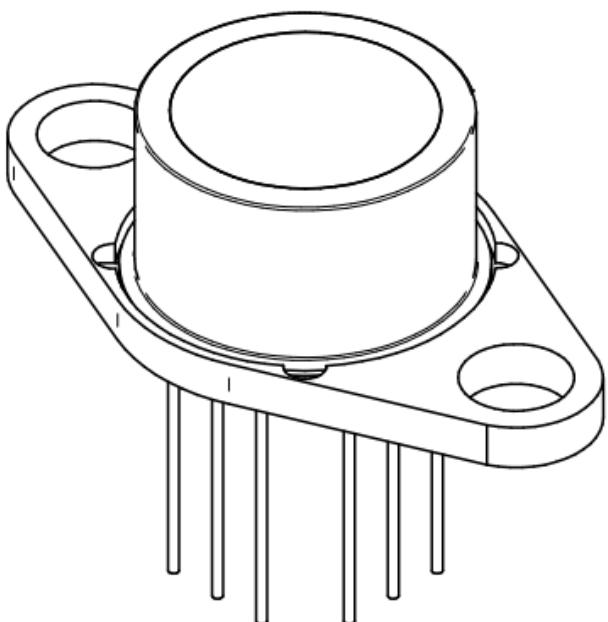
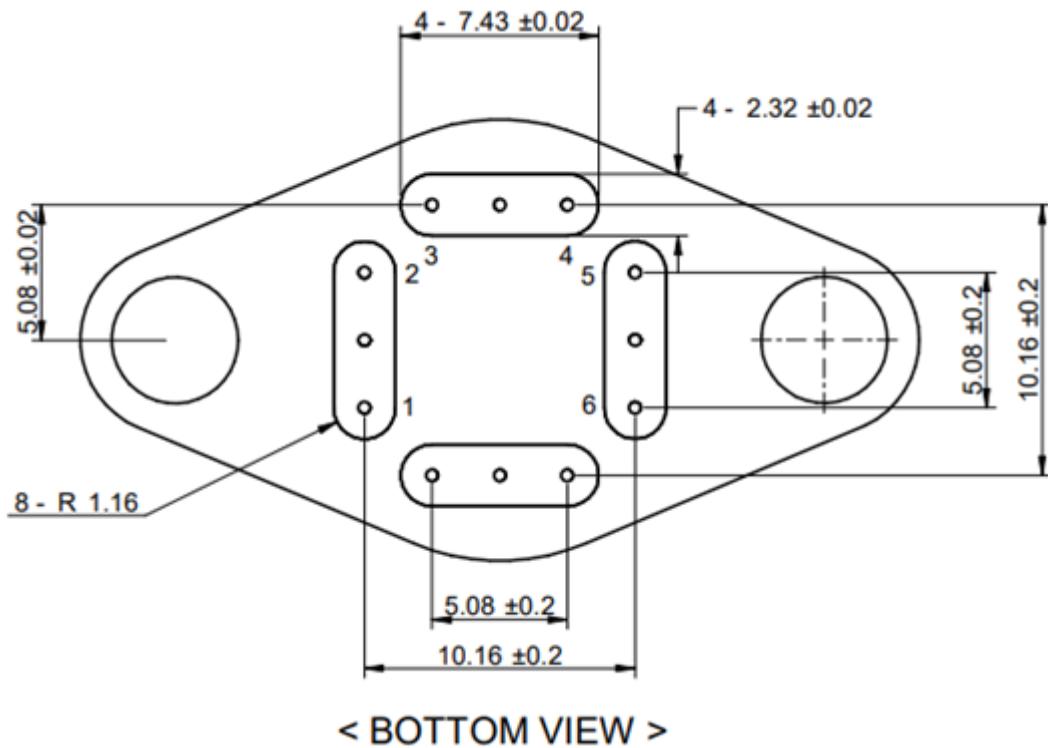
(Unit : mm)



< TOP VIEW >



SECTION A-A



| No. | Description |
|-----|---------------------|
| 1 | TEC (-) |
| 2 | TEC (+) |
| 3 | APD Anode (with Qr) |
| 4 | APD Cathode |
| 5 | Thermistor1 |
| 6 | Thermistor2 |

Figure 1. Mechanical Dimension and Standard PIN map

Other Requirements

Precautions for use

This device is susceptible to damage as a result of ESD(electrostatic discharge). Use of ground straps, anti static mats, and other standard ESD protective equipment is recommended when handling or testing an InGaAs PIN/APD or any other junction photodiode. Soldering temperature of the leads should not exceed 350 °C for more than 3 seconds.

Ordering Information

WPGSNGMLJNNCFO (NFAD with TEC TO-8 Free Space type with standard PIN map)

WPRDNGMLCNNCFO (NFAD with TEC TO-8 Free Space type with customized PIN map)